TEXAS INSTRUMENTS

LMC6482-MIL CMOSデュアル・レール・ツー・レール入力および出力オペアンプ

1 特長

- 特に記述のない限り標準値
- レール・ツー・レール入力同相電圧範囲(全温度範囲にわたって保証)
- レール・ツー・レール出力(電源レールの20mV以内、100kΩ負荷)
- 3V、5V、15Vでの性能を保証
- 非常に優れたCMRRおよびPSRR: 82dB
- 非常に低い入力電流: 20fA
- 高い電圧ゲイン(R L = 500kΩ): 130dB
- 2kΩおよび600Ω負荷について動作を規定
- パワー・グッド出力
- VSSOPパッケージで供給

2 アプリケーション

- データ収集システム
- トランスデューサ・アンプ
- 携帯型分析測定器
- 医療用計測機器
- アクティブ・フィルタ、ピーク検出器、サンプル・アンド・ホールド、pHメータ、電流ソース
- TLC272、TLC277の改良版

3 概要

LMC6482-MILデバイスは、両方の電源レールを超える同相範囲を実現しています。レール・ツー・レール性能と、高いCMRRによる非常に優れた精度から、レール・ツー・レール入力アンプの中でも出色の製品です。このデバイスは、データ収集など大きな入力信号範囲を必要とするシステムに理想的です。また、LMC6482-MILはTLC272やTLC277など同相範囲の限られたアンプを使用する回路のアップグレードとしても優れています。

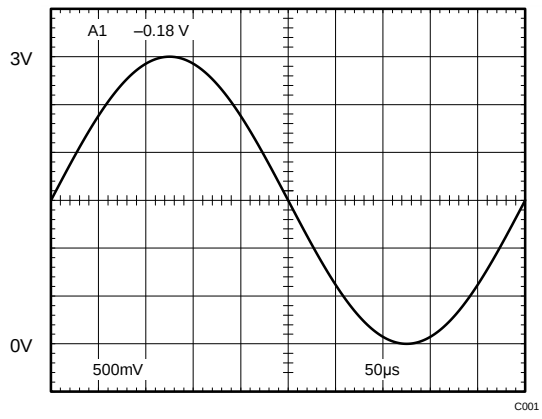
LMC6482-MILのレール・ツー・レール出力により、低電圧および単一電源のシステムで最大のダイナミック信号範囲が保証されます。デバイスの最低600Ωの負荷について、レール・ツー・レール出力が保証されます。低電圧特性と低消費電力が保証されているため、LMC6482-MILはバッテリで動作するシステムに特に適しています。LMC6482-MILは、SOIC-8デバイスのほぼ半分の大きさである、VSSOPパッケージでも供給されます。これらと同じ特長を持つクワッドCMOSオペアンプについては、LMC6484のデータシートを参照してください。

製品情報(1)

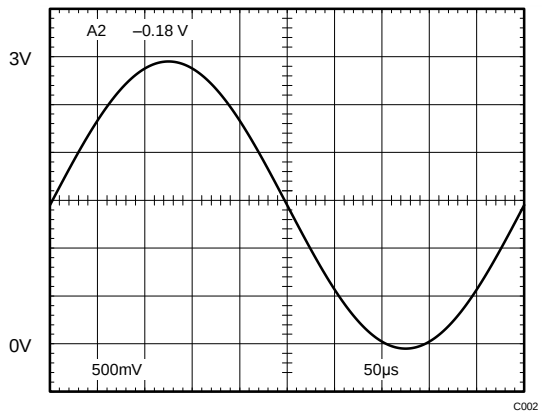
型番	パッケージ	本体サイズ(公称)
LMC6482-MIL	SOIC (8)	4.90mm×3.91mm
	VSSOP (8)	3.00mm×3.00mm
	PDIP (8)	9.81mm×6.35mm

(1) 提供されているすべてのパッケージについては、巻末の注文情報を参照してください。

レール・ツー・レール入力



レール・ツー・レール出力



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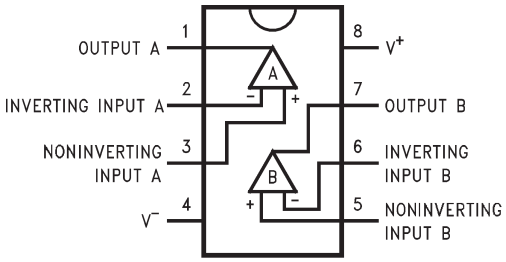
4 改訂履歴

日付	改訂内容	注
	*	初版

5 Pin Configuration and Functions

D, DGK and P Packages
8-Pin SOIC, VSSOP and PDIP
(Top View)



Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
1	OUTPUT A	O	Output for Amplifier A
2	INVERTING INPUT A	I	Inverting input for Amplifier A
3	NONINVERTING INPUT A	I	Noninverting input for Amplifier A
4	V^-	P	Negative supply voltage input
5	NONINVERTING INPUT B	I	Noninverting input for Amplifier B
6	INVERTING INPUT B	I	Inverting input for Amplifier B
7	OUTPUT B	O	Output for Amplifier B
8	V^+	P	Positive supply voltage input

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)(2)

	MIN	MAX	UNIT
Differential Input Voltage		±Supply Voltage	
Voltage at Input/Output Pin	(V^-) −0.3	(V^+) +0.3	V
Supply Voltage ($V^+ - V^-$)		16	V
Current at Input Pin (3)	−5	5	mA
Current at Output Pin (4) (5)	−30	30	mA
Current at Power Supply Pin		40	mA
Lead Temperature (Soldering, 10 sec.)		260	°C
Junction Temperature (6)		150	°C
Storage temperature, T_{stg}	−65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.
(3) Limiting input pin current is only necessary for input voltages that exceed absolute maximum input voltage ratings.
(4) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of ±30 mA over long term may adversely affect reliability.
(5) Do not short circuit output to V^+, when V^+ is greater than 13 V or reliability will be adversely affected.
(6) The maximum power dissipation is a function of $T_{J(max)}$, $R_{\theta JA}$, and T_A. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly into a PC board.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±1500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
Supply Voltage		3	15.5	V
Junction Temperature Range	LMC6482M	–55	125	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.4 Thermal Information

THERMAL METRIC (1)		LMC6482-MIL D (SOIC) 8 PINS	LMC6482-MIL DGK (VSSOP) 8 PINS	LMC6482-MIL P (PDIP) 8 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	155	194	90	°C/W

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.

6.5 Electrical Characteristics for V^+ = 5 V

Unless otherwise specified, all limits specified for T_J = 25°C, V^+ = 5 V, V^- = 0 V, V_{CM} = V_O = V^+/2 and R_L > 1 M.

PARAMETER		TEST CONDITIONS	T_J = 25°C			At Temperature Extremes (1)			UNIT
			MIN	TYP (2)	MAX (3)	MIN	TYP (2)	MAX (3)	
DC Electrical Characteristics									
V_{OS}	Input Offset Voltage			0.11	3			3.8	mV
TCV_{OS}	Input Offset Voltage Average Drift			1					µV/°C
I_B	Input Current	See (4)		0.02				10	pA
I_{OS}	Input Offset Current	See (4)		0.01				5	pA
C_{IN}	Common-Mode Input Capacitance			3					pF
R_{IN}	Input Resistance			10					TeraΩ
CMRR	Common-Mode Rejection Ratio	0 V ≤ V_{CM} ≤ 15 V V^+ = 15 V	65	82		60			dB
		0 V ≤ V_{CM} ≤ 5 V V^+ = 5 V	65	82		60			
+PSRR	Positive Power Supply Rejection Ratio	5 V ≤ V^+ ≤ 15 V, V^- = 0 V V_O = 2.5 V	65	82		60			dB
−PSRR	Negative Power Supply Rejection Ratio	−5 V ≤ V^- ≤ −15 V, V^+ = 0 V V_O = −2.5 V	65	82		60			dB

(1) See *Recommended Operating Conditions* for operating temperature ranges.
(2) Typical Values represent the most likely parametric norm.
(3) All limits are specified by testing or statistical analysis.
(4) Ensured limits are dictated by tester limitations and not device performance. Actual performance is reflected in the typical value.

Electrical Characteristics for V^+ = 5 V (continued)

Unless otherwise specified, all limits specified for T_J = 25°C, V^+ = 5 V, V^- = 0 V, V_{CM} = V_O = V^+/2 and R_L > 1 M.

PARAMETER		TEST CONDITIONS		T_J = 25°C			At Temperature Extremes(1)			UNIT
				MIN	TYP(2)	MAX(3)	MIN	TYP(2)	MAX(3)	
V_{CM}	Input Common-Mode Voltage Range	V^+ = 5 V and 15 V For CMRR ≥ 50 dB			V^- − 0.3	−0.25			0	V
				V^+ + 0.25	V^+ + 0.3		V^+			
A_V	Large Signal Voltage Gain	R_L = 2 kΩ(5)(4)	Sourcing	120	666		60			V/mV
			Sinking	35	75		18			
		R_L = 600 Ω(5)(4)	Sourcing	50	300		25			
			Sinking	15	35		8			
V_O	Output Swing	V^+ = 5 V R_L = 2 kΩ to V^+/2		4.8	4.9		4.7			V
					0.1	0.18			0.24	
		V^+ = 5 V R_L = 600 Ω to V^+/2		4.5	4.7		4.24			V
					0.3	0.5			0.65	
		V^+ = 15 V R_L = 2k Ω to V^+/2		14.4	14.7		14.2			V
					0.16	0.32			0.45	
		V^+ = 15 V R_L = 600 Ω to V^+/2		13.4	14.1		13			V
					0.5	1			1.3	
I_{SC}	Output Short Circuit Current V^+ = 5 V	Sourcing, V_O = 0 V		16	20		10			mA
		Sinking, V_O = 5 V		11	15		8			
I_{SC}	Output Short Circuit Current V^+ = 15 V	Sourcing, V_O = 0 V		28	30		20			mA
		Sinking, V_O = 12 V(6)		30	30		22			
I_S	Supply Current	Both Amplifiers V^+ = +5 V, V_O = V^+/2			1	1.4			1.9	mA
		Both Amplifiers V^+ = 15 V, V_O = V^+/2			1.3	1.6			2	
AC Electrical Characteristics										
SR	Slew Rate	See (7)		0.9	1.3		0.54			V/μs
GBW	Gain-Bandwidth Product	V^+ = 15 V			1.5					MHz
φ_m	Phase Margin				50					Deg
G_m	Gain Margin				15					dB
	Amp-to-Amp Isolation	See (8)			150					dB
e_n	Input-Referred Voltage Noise	F = 1 kHz V_{cm} = 1 V			37					nV/√Hz
I_n	Input-Referred Current Noise	F = 1 kHz			0.03					pA/√Hz
T.H.D.	Total Harmonic Distortion	F = 10 kHz, A_V = −2 R_L = 10 kΩ, V_O = 4.1 V_{PP}			0.01%					
		F = 10 kHz, A_V = −2 R_L = 10 kΩ, V_O = 8.5 V_{PP} V^+ = 10 V			0.01%					

(5) V^+ = 15 V, V_{CM} = 7.5 V and R_L connected to 7.5 V. For Sourcing tests, 7.5 V ≤ V_O ≤ 11.5 V. For Sinking tests, 3.5 V ≤ V_O ≤ 7.5 V.
(6) Do not short circuit output to V^+, when V^+ is greater than 13 V or reliability will be adversely affected.
(7) V + = 15V. Connected as Voltage Follower with 10V step input. Number specified is the slower of either the positive or negative slew rates.
(8) Input referred, V^+ = 15 V and R_L = 100 kΩ connected to 7.5 V. Each amp excited in turn with 1 kHz to produce V_O = 12 V_{PP}.

6.6 Electrical Characteristics for V^+ = 3 V

Unless otherwise specified, all limits specified for T_J = 25°C, V^+ = 3V, V^- = 0V, V_{CM} = V_O = V^+/2 and R_L > 1M.

PARAMETER		TEST CONDITIONS	T_J = 25°C			At Temperature Extremes(1)			UNIT
			MIN	TYP(2)	MAX(3)	MIN	TYP(2)	MAX(3)	
DC Electrical Characteristics									
V_{OS}	Input Offset Voltage			0.9	3			3.8	mV
TCV_{OS}	Input Offset Voltage Average Drift			2					µV/°C
I_B	Input Bias Current			0.02					pA
I_{OS}	Input Offset Current			0.01					pA
CMRR	Common Mode Rejection Ratio	0 V ≤ V_{CM} ≤ 3 V	60	74					dB
PSRR	Power Supply Rejection Ratio	3 V ≤ V^+ ≤ 15 V, V^- = 0 V	60	80					dB
V_{CM}	Input Common-Mode Voltage Range	For CMRR ≥ 50 dB		V^- −0.25	0				V
			V^+	V^+ + 0.25					V
V_O	Output Swing	R_L = 2 kΩ to V^+/2		2.8					V
				0.2					V
		R_L = 600 Ω to V^+/2	2.5	2.7					V
				0.37	0.6				V
I_S	Supply Current	Both Amplifiers		0.825	1.2			1.6	mA
AC Electrical Characteristics									
SR	Slew Rate	See (4)		0.9					V/µs
GBW	Gain-Bandwidth Product			1					MHz
T.H.D.	Total Harmonic Distortion	F = 10 kHz, A_V = −2 R_L = 10 kΩ, V_O = 2 V_{PP}		0.01%					

(1) See *Recommended Operating Conditions* for operating temperature ranges.
(2) Typical Values represent the most likely parametric norm.
(3) All limits are specified by testing or statistical analysis.
(4) Connected as voltage Follower with 2-V step input. Number specified is the slower of either the positive or negative slew rates.

6.7 Typical Characteristics

V_S = 15 V, Single Supply, T_A = 25°C unless otherwise specified

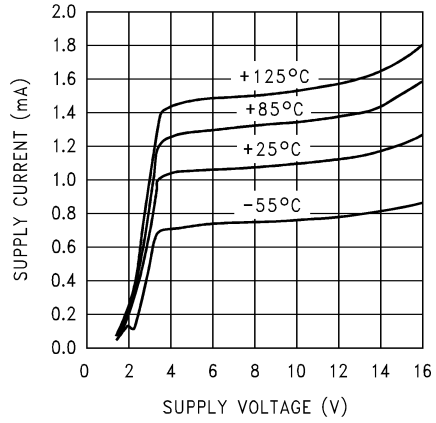


Figure 1. Supply Current vs. Supply Voltage

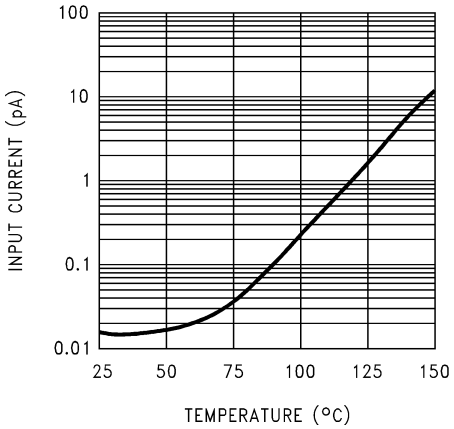


Figure 2. Input Current vs. Temperature

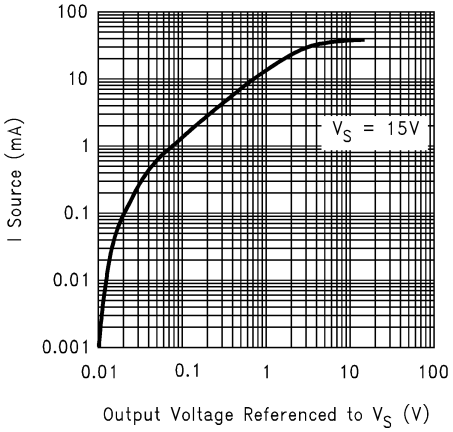


Figure 3. Sourcing Current vs. Output Voltage

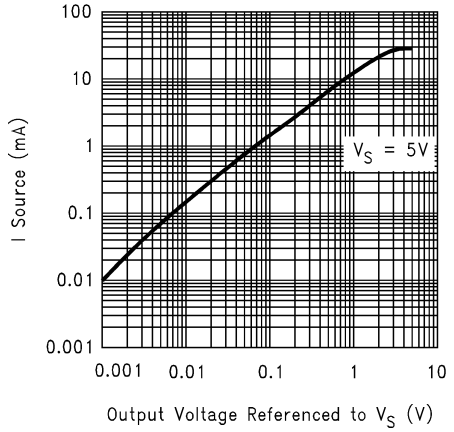


Figure 4. Sourcing Current vs. Output Voltage

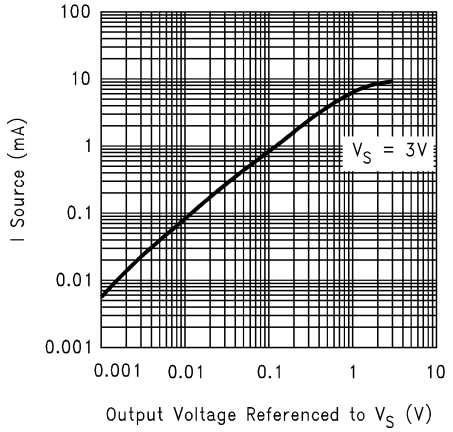


Figure 5. Sourcing Current vs. Output Voltage

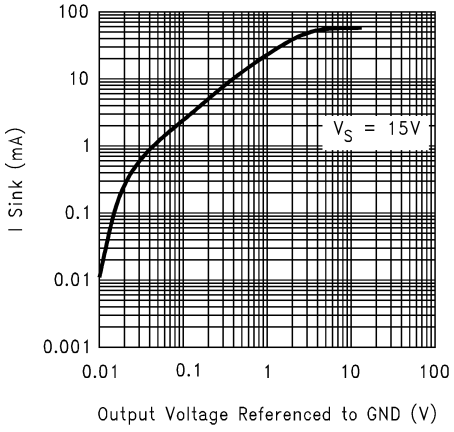


Figure 6. Sinking Current vs. Output Voltage

Typical Characteristics (continued)

V_S = 15 V, Single Supply, T_A = 25°C unless otherwise specified

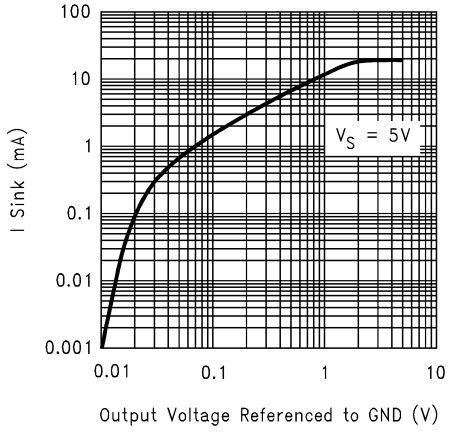


Figure 7. Sinking Current vs. Output Voltage

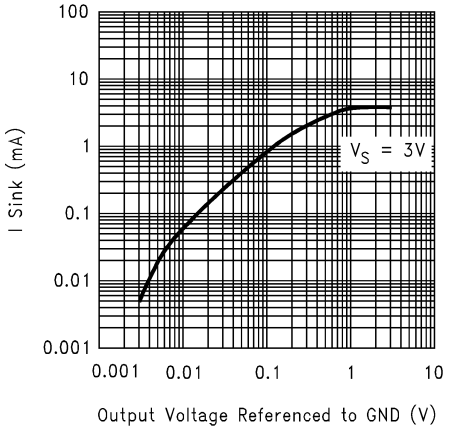


Figure 8. Sinking Current vs. Output Voltage

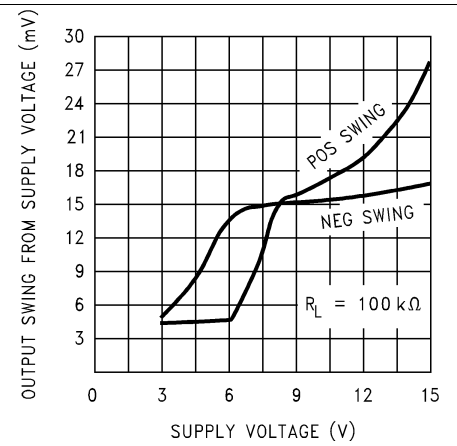


Figure 9. Output Voltage Swing vs. Supply Voltage

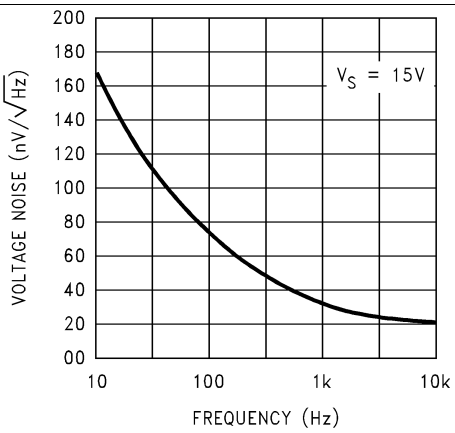


Figure 10. Input Voltage Noise vs. Frequency

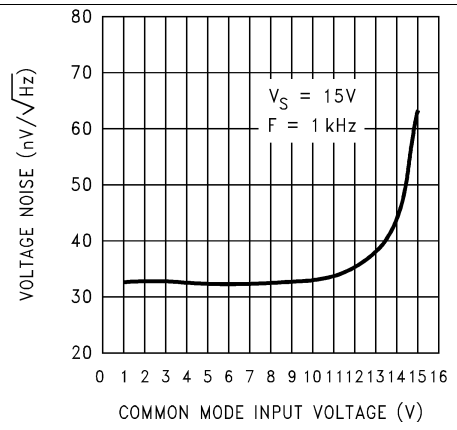


Figure 11. Input Voltage Noise vs. Input Voltage

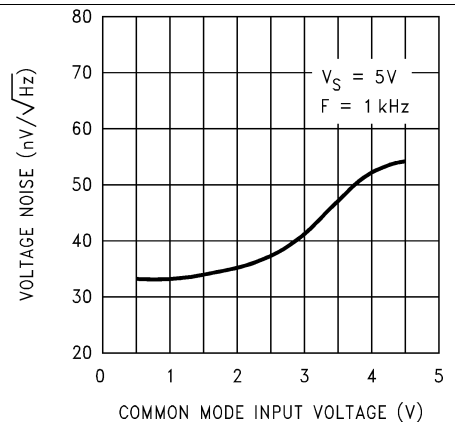


Figure 12. Input Voltage Noise vs. Input Voltage

Typical Characteristics (continued)

V_S = 15 V, Single Supply, T_A = 25°C unless otherwise specified

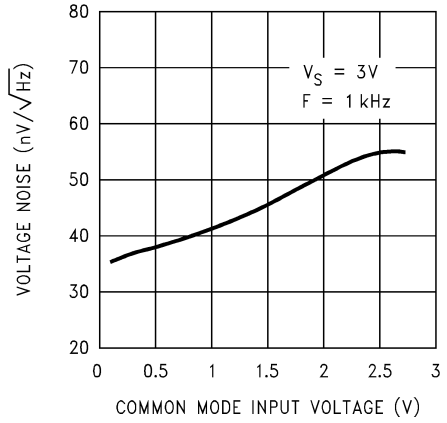


Figure 13. Input Voltage Noise vs. Input Voltage

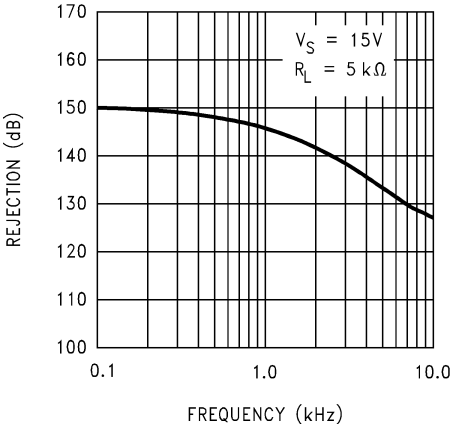


Figure 14. Crosstalk Rejection vs. Frequency

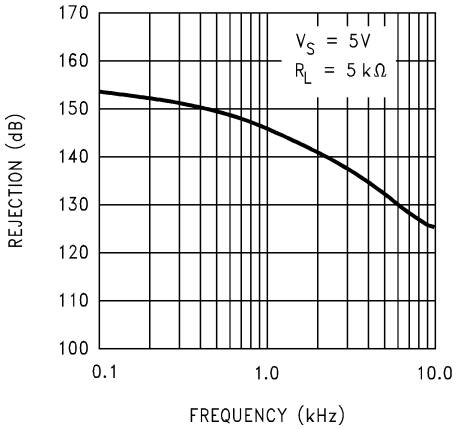


Figure 15. Crosstalk Rejection vs. Frequency

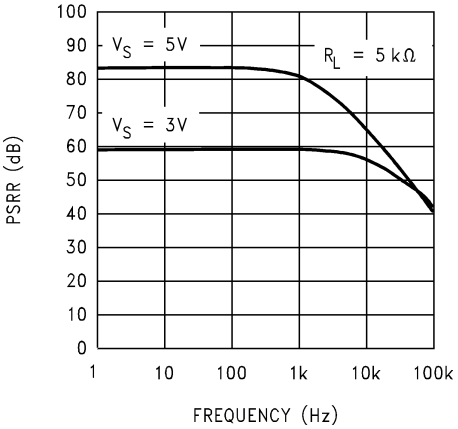


Figure 16. Positive PSRR vs. Frequency

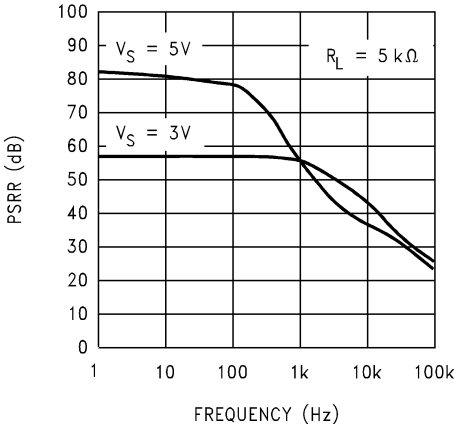


Figure 17. Negative PSRR vs. Frequency

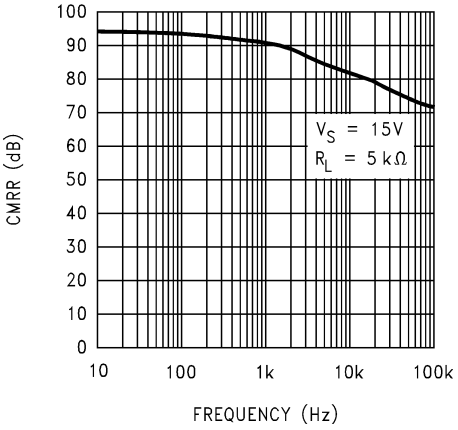


Figure 18. CMRR vs. Frequency

Typical Characteristics (continued)

V_S = 15 V, Single Supply, T_A = 25°C unless otherwise specified

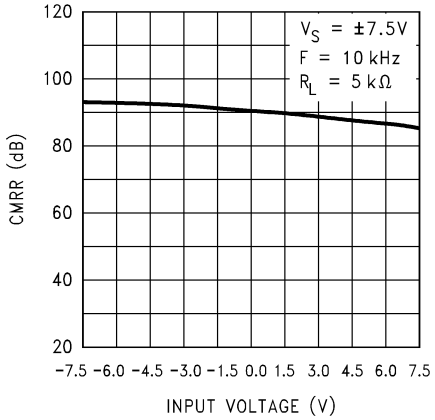


Figure 19. CMRR vs. Input Voltage

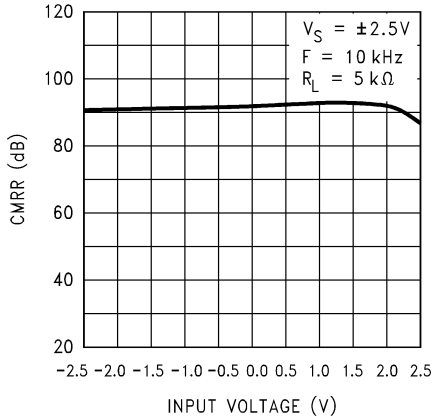


Figure 20. CMRR vs. Input Voltage

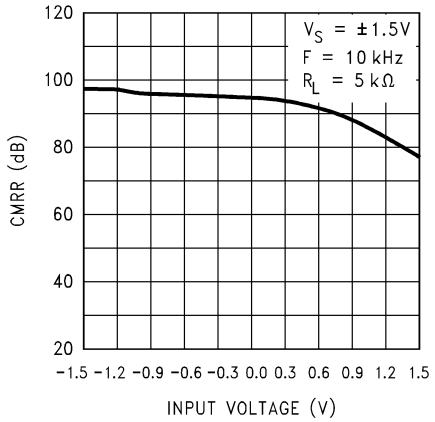


Figure 21. CMRR vs. Input Voltage

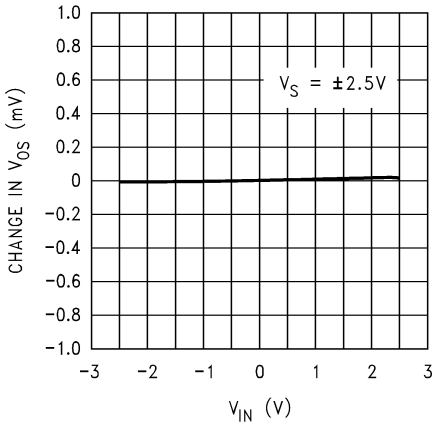


Figure 22. Δv_{OS} vs. CMR

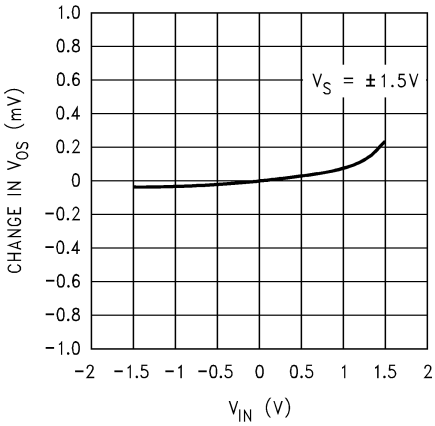


Figure 23. Δv_{OS} vs. CMR

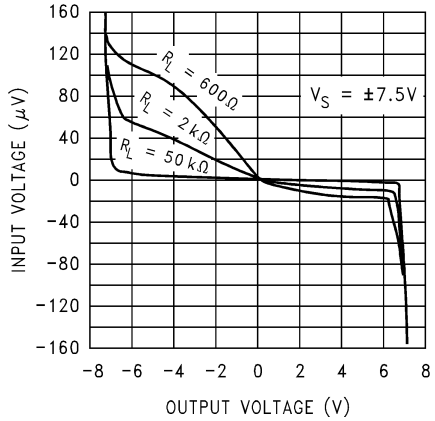


Figure 24. Input Voltage vs. Output Voltage

Typical Characteristics (continued)

V_S = 15 V, Single Supply, T_A = 25°C unless otherwise specified

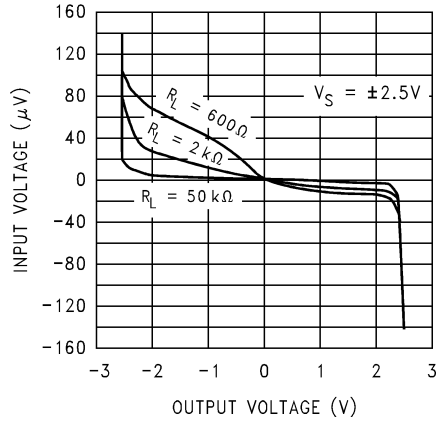


Figure 25. Input Voltage vs. Output Voltage

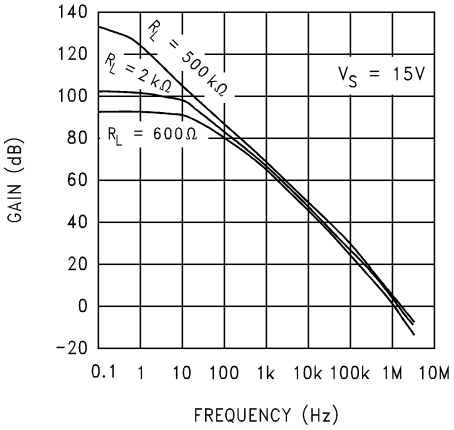


Figure 26. Open-Loop Frequency Response

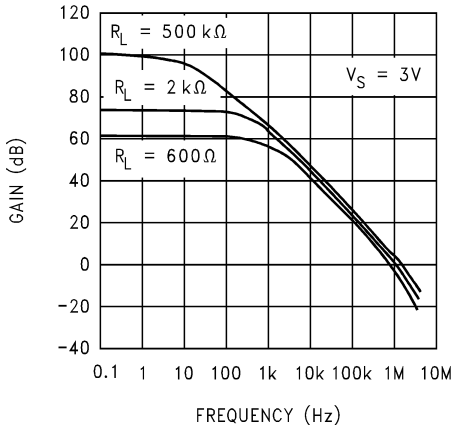


Figure 27. Open-Loop Frequency Response

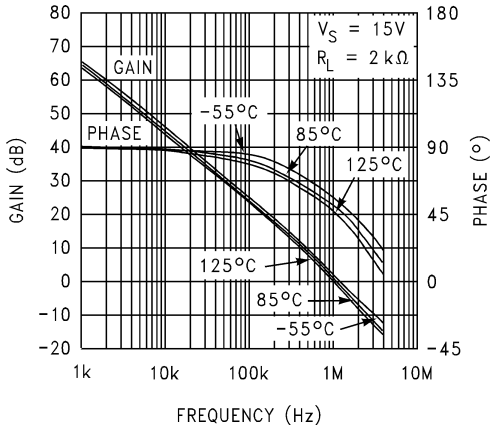


Figure 28. Open-Loop Frequency Response vs. Temperature

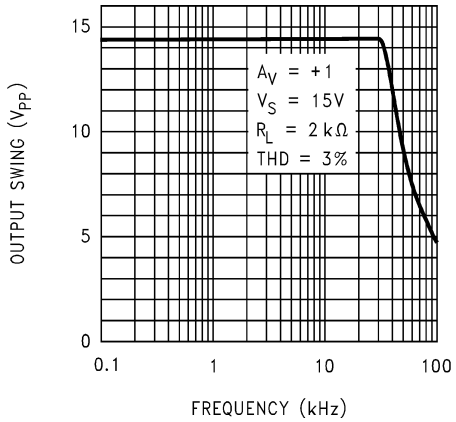


Figure 29. Maximum Output Swing vs. Frequency

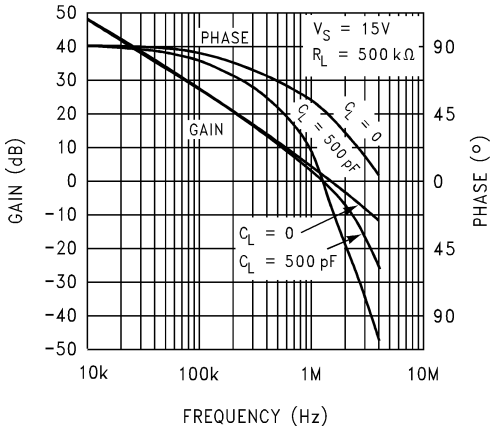


Figure 30. Gain and Phase vs. Capacitive Load

Typical Characteristics (continued)

V_S = 15 V, Single Supply, T_A = 25°C unless otherwise specified

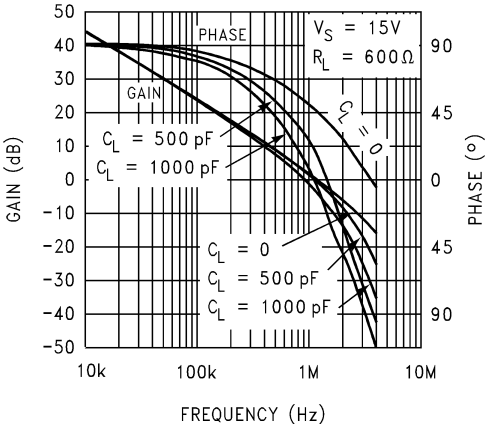


Figure 31. Gain and Phase vs. Capacitive Load

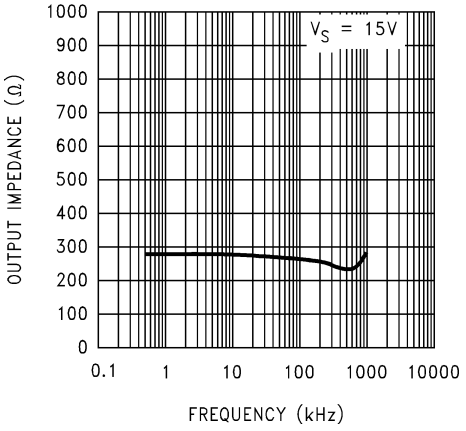


Figure 32. Open-Loop Output Impedance vs. Frequency

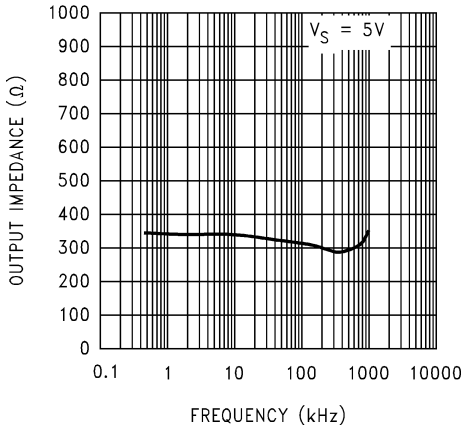


Figure 33. Open-Loop Output Impedance vs. Frequency

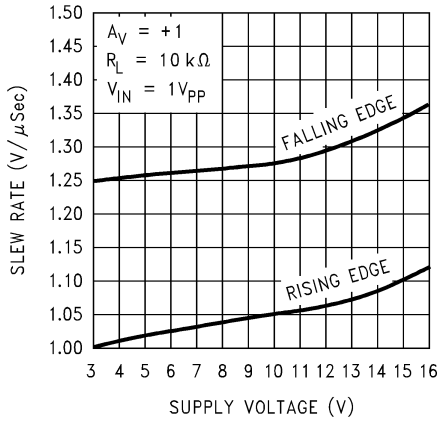


Figure 34. Slew Rate vs. Supply Voltage

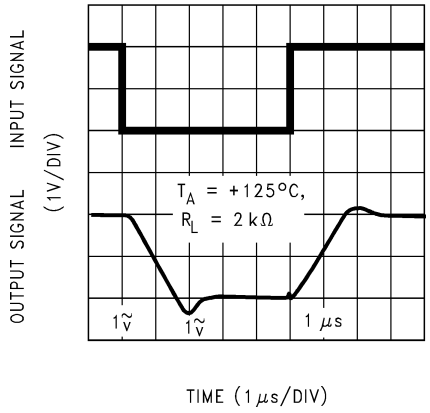


Figure 35. Noninverting Large Signal Pulse Response

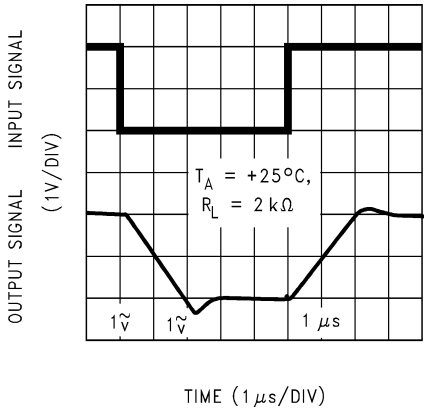


Figure 36. Noninverting Large Signal Pulse Response

Typical Characteristics (continued)

V_S = 15 V, Single Supply, T_A = 25°C unless otherwise specified

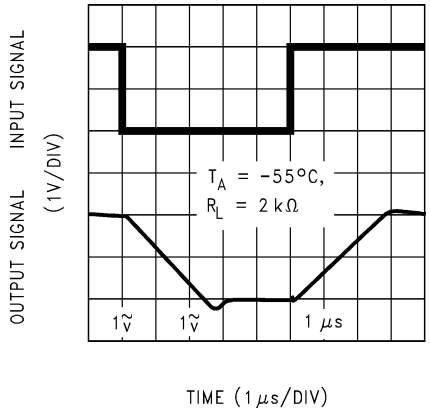


Figure 37. Noninverting Large Signal Pulse Response

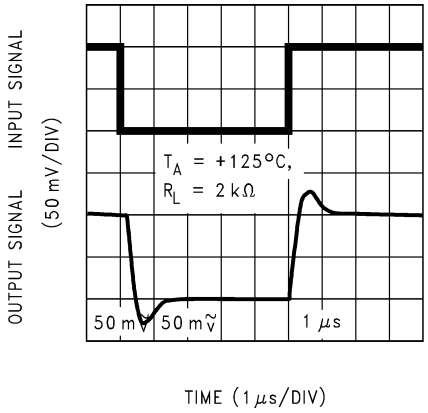


Figure 38. Noninverting Small Signal Pulse Response

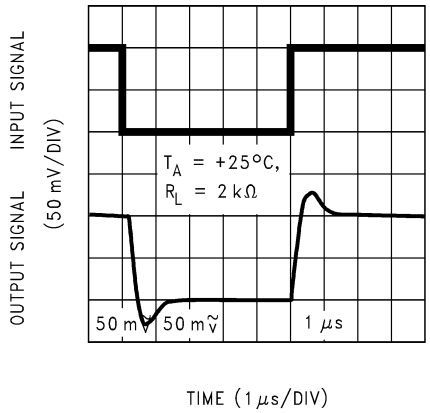


Figure 39. Noninverting Small Signal Pulse Response

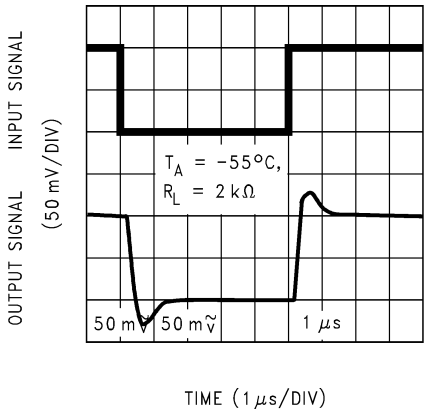


Figure 40. Noninverting Small Signal Pulse Response

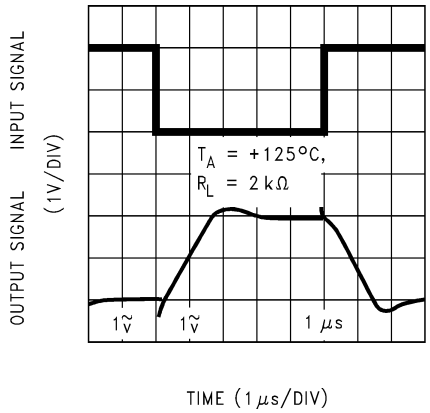


Figure 41. Inverting Large Signal Pulse Response

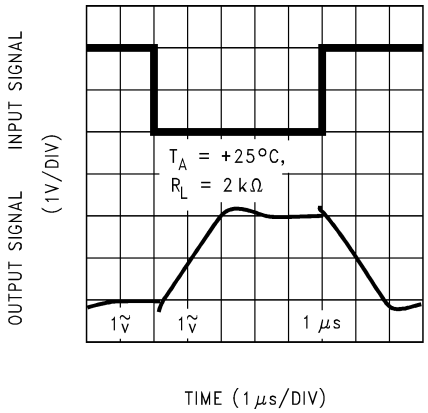


Figure 42. Inverting Large Signal Pulse Response

Typical Characteristics (continued)

V_S = 15 V, Single Supply, T_A = 25°C unless otherwise specified

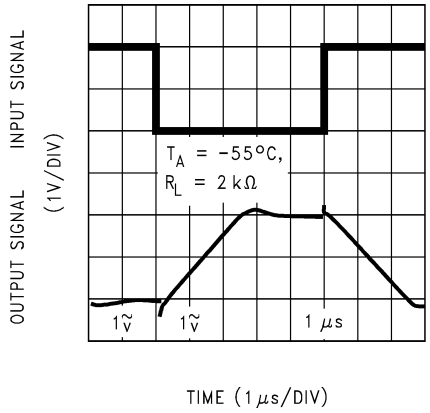


Figure 43. Inverting Large Signal Pulse Response

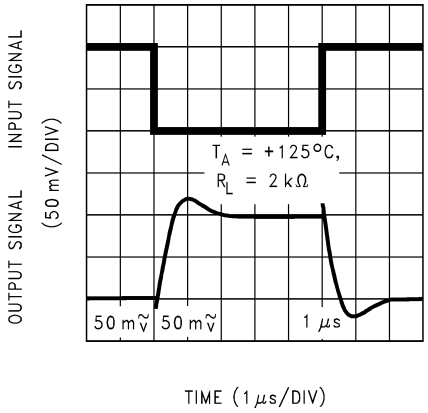


Figure 44. Inverting Small Signal Pulse Response

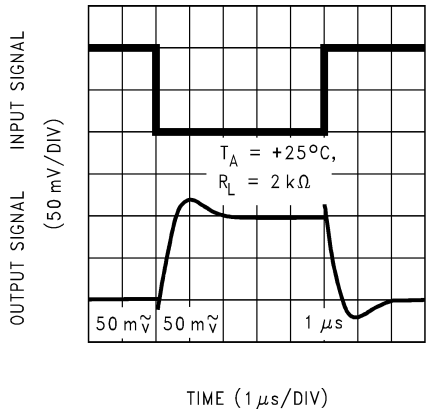


Figure 45. Inverting Small Signal Pulse Response

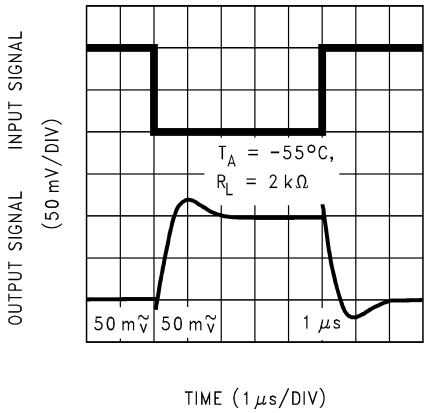


Figure 46. Inverting Small Signal Pulse Response

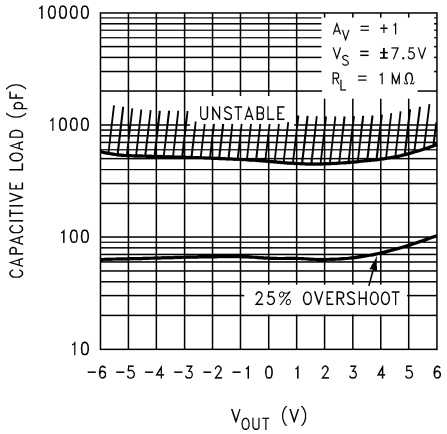


Figure 47. Stability vs. Capacitive Load

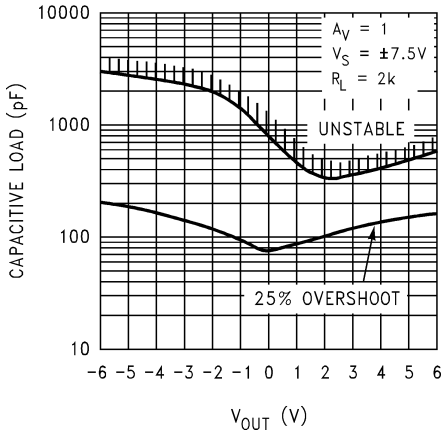


Figure 48. Stability vs. Capacitive Load

Typical Characteristics (continued)

V_S = 15 V, Single Supply, T_A = 25°C unless otherwise specified

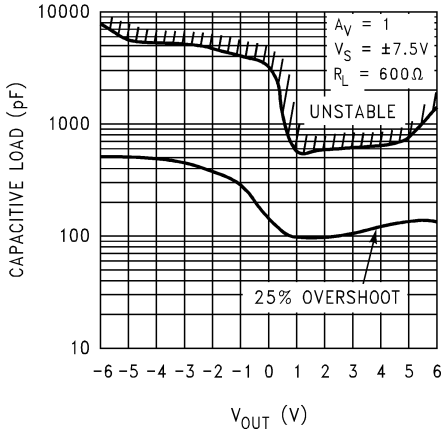


Figure 49. Stability vs. Capacitive Load

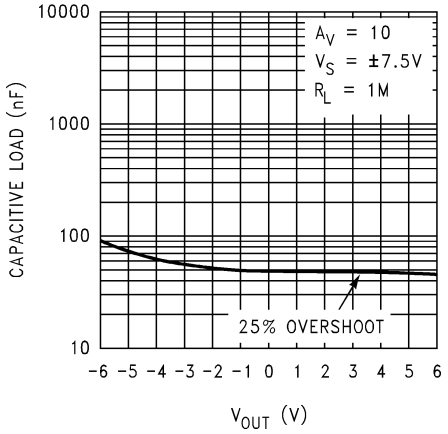


Figure 50. Stability vs. Capacitive Load

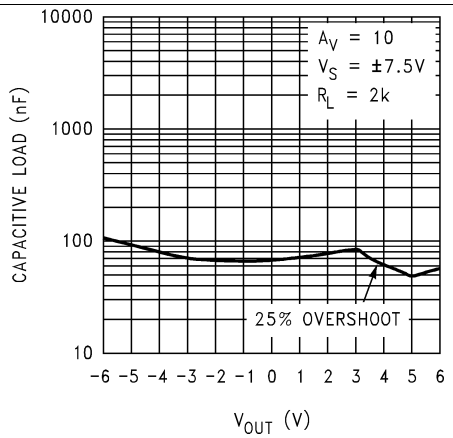


Figure 51. Stability vs. Capacitive Load

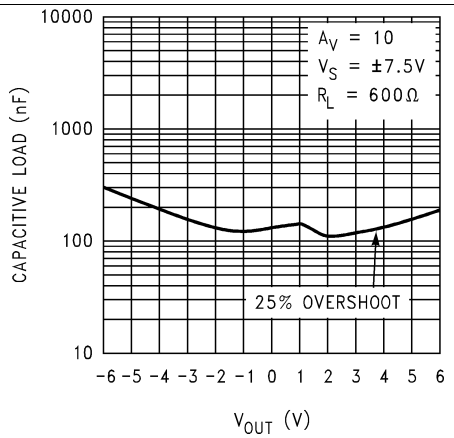


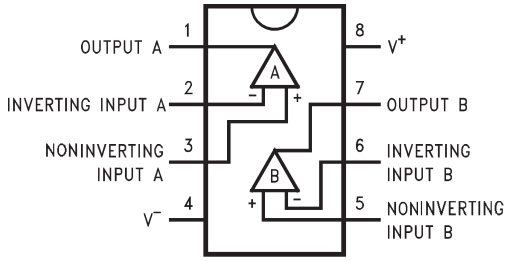
Figure 52. Stability vs. Capacitive Load

7 Detailed Description

7.1 Overview

The LMC6482-MIL is a dual CMOS operational amplifier that supports both rail-to-rail inputs and outputs. It may be operated in both dual supply mode and single supply mode.

7.2 Functional Block Diagram



7.3 Feature Description

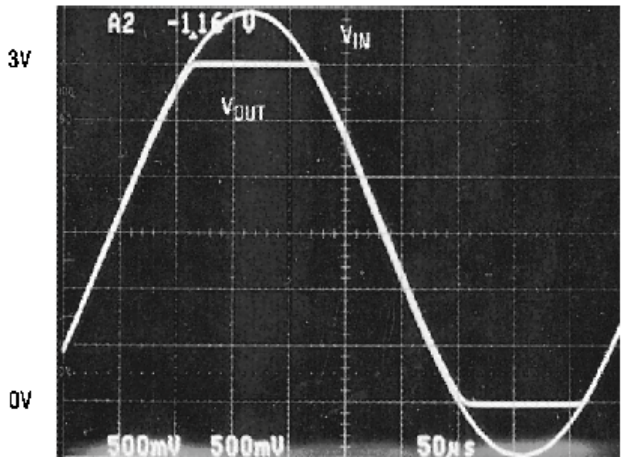
7.3.1 Amplifier Topology

The LMC6482-MIL incorporates specially designed wide-compliance range current mirrors and the body effect to extend input common-mode range to each supply rail. Complementary paralleled differential input stages, like the type used in other CMOS and bipolar rail-to-rail input amplifiers, were not used because of their inherent accuracy problems due to CMRR, crossover distortion, and open-loop gain variation.

The LMC6482-MILs input stage design is complemented by an output stage capable of rail-to-rail output swing even when driving a large load. Rail-to-rail output swing is obtained by taking the output directly from the internal integrator instead of an output buffer stage.

7.3.2 Input Common-Mode Voltage Range

Unlike Bi-FET amplifier designs, the LMC6482-MIL does not exhibit phase inversion when an input voltage exceeds the negative supply voltage. Figure 53 shows an input voltage exceeding both supplies with no resulting phase inversion on the output.

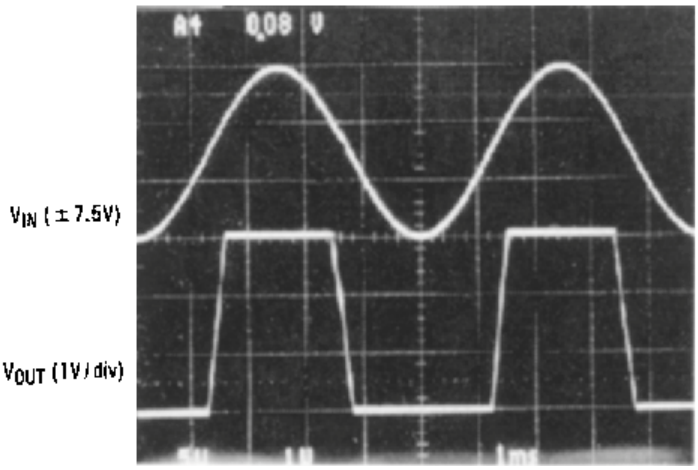


An input voltage signal exceeds the LMC6482-MIL power supply voltages with no output phase inversion.

Figure 53. Input Voltage

The absolute maximum input voltage is 300 mV beyond either supply rail at room temperature. Voltages greatly exceeding this absolute maximum rating, as in Figure 54, can cause excessive current to flow in or out of the input pins possibly affecting reliability.

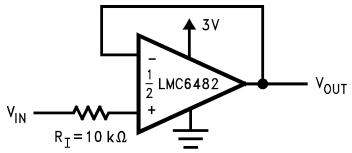
Feature Description (continued)



A ±7.5-V input signal greatly exceeds the 3-V supply in Figure 55 causing no phase inversion due to R_I.

Figure 54. Input Signal

Applications that exceed this rating must externally limit the maximum input current to ±5 mA with an input resistor (R_I) as shown in Figure 55.



R_I input current protection for voltages exceeding the supply voltages.

Figure 55. R_I Input Current Protection for Voltages Exceeding the Supply Voltages

7.3.3 Rail-to-Rail Output

The approximated output resistance of the LMC6482-MIL is 180-Ω sourcing and 13-0Ω sinking at V_S = 3 V and 110-Ω sourcing and 80-Ω sinking at Vs = 5 V. Using the calculated output resistance, maximum output voltage swing can be estimated as a function of load.

7.4 Device Functional Modes

The LMC6482-MIL may be used in applications where each amplifier channel is used independently, or in applications in which the channels are cascaded. See *Typical Applications* for more information.

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

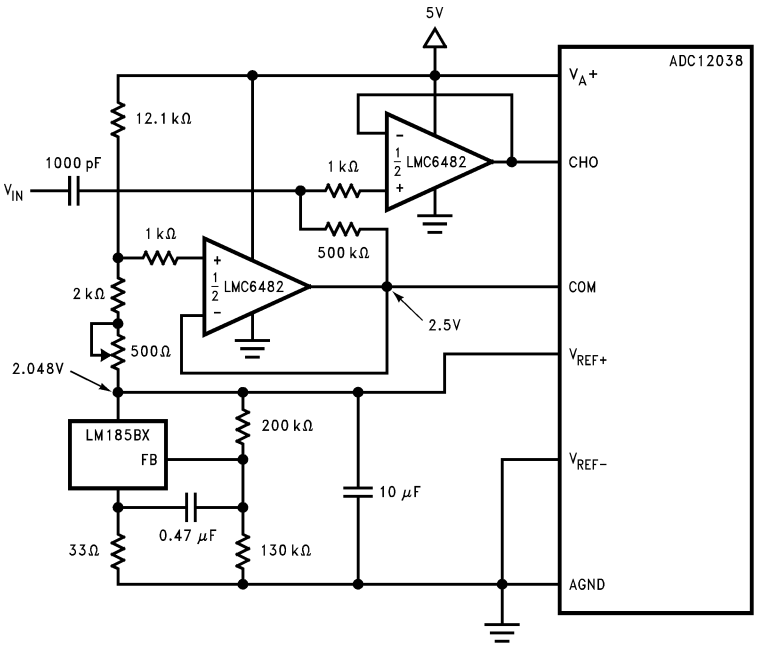
8.1.1 Upgrading Applications

The LMC6484 quads and LMC6482-MIL duals have industry-standard pin outs to retrofit existing applications. System performance can be greatly increased by the features of the LMC6482-MIL. The key benefit of designing in the LMC6482-MIL is increased linear signal range. Most op-amps have limited input common-mode ranges. Signals that exceed this range generate a nonlinear output response that persists long after the input signal returns to the common-mode range.

Linear signal range is vital in applications such as filters where signal peaking can exceed input common-mode ranges resulting in output phase inversion or severe distortion.

8.1.2 Data Acquisition Systems

Low power, single supply data acquisition system solutions are provided by buffering the ADC12038 with the LMC6482-MIL (Figure 56). Capable of using the full supply range, the LMC6482-MIL does not require input signals to be scaled down to meet limited common-mode voltage ranges. The LMC4282 CMRR of 82 dB maintains integral linearity of a 12-bit data acquisition system to ±0.325 LSB. Other rail-to-rail input amplifiers with only 50 dB of CMRR will degrade the accuracy of the data acquisition system to only 8 bits.



Operating from the same supply voltage, the LMC6482-MIL buffers the ADC12038 maintaining excellent accuracy.

Figure 56. Buffering the ADC12038 With the LMC6482-MIL

Application Information (continued)

8.1.3 Instrumentation Circuits

The LMC6482-MIL has the high input impedance, large common-mode range and high CMRR needed for designing instrumentation circuits. Instrumentation circuits designed with the LMC6482-MIL can reject a larger range of common-mode signals than most in-amps. This makes instrumentation circuits designed with the LMC6482-MIL an excellent choice of noisy or industrial environments. Other applications that benefit from these features include analytic medical instruments, magnetic field detectors, gas detectors, and silicon-based transducers.

A small valued potentiometer is used in series with R_g to set the differential gain of the 3-op-amp instrumentation circuit in Figure 57. This combination is used instead of one large valued potentiometer to increase gain trim accuracy and reduce error due to vibration.

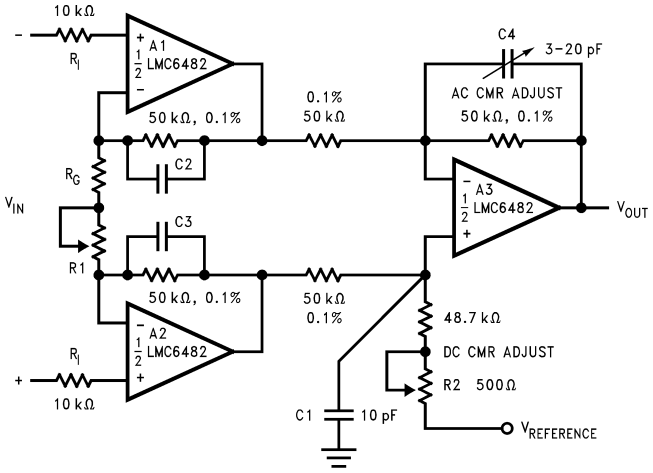


Figure 57. Low Power 3-Op-Amp Instrumentation Amplifier

A 2-op-amp instrumentation amplifier designed for a gain of 100 is shown in Figure 58. Low sensitivity trimming is made for offset voltage, CMRR, and gain. Low cost and low power consumption are the main advantages of this 2-op-amp circuit.

Higher frequency and larger common-mode range applications are best facilitated by a 3-op-amp instrumentation amplifier.

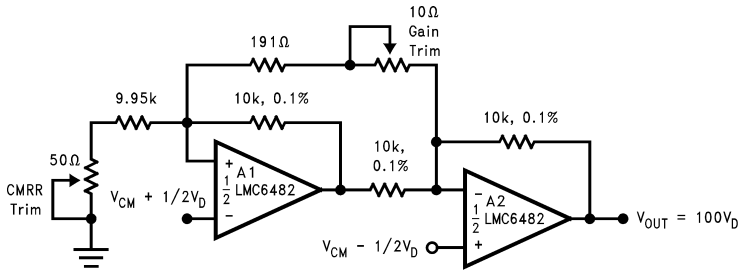


Figure 58. Low-Power Two-Op-Amp Instrumentation Amplifier

8.1.4 Spice Macromodel

A spice macromodel is available for the LMC6482-MIL. This model includes accurate simulation of the following:

- Input common-mode voltage range
- Frequency and transient response
- GBW dependence on loading conditions
- Quiescent and dynamic supply current
- Output swing dependence on loading conditions

Application Information (continued)

Many more characteristics are listed on the macromodel disk.

Contact your local TI sales office to obtain an operational amplifier spice model library disk.

8.2 Typical Applications

8.2.1 3-V Single Supply Buffer Circuit

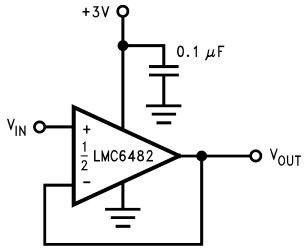


Figure 59. 3-V Single Supply Buffer Circuit

8.2.1.1 Design Requirements

For best performance, ensure that the input voltage swing is between V+ and V-.

Ensure that the input does not exceed the common-mode input range.

To reduce the risk of destabilizing the output, use resistive isolation on the output when driving capacitive loads (see the *Detailed Design Procedure* section).

When large feedback resistors are used, it may be necessary to compensate for parasitic capacitance on the input. See the *Detailed Design Procedure* section.

8.2.1.2 Detailed Design Procedure

8.2.1.2.1 Capacitive Load Compensation

Capacitive load compensation can be accomplished using resistive isolation as shown in Figure 60. This simple technique is useful for isolating the capacitive inputs of multiplexers and A/D converters.

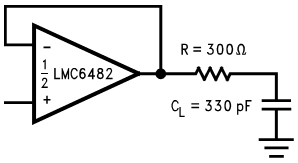


Figure 60. Resistive Isolation of a 330-pF Capacitive Load

Typical Applications (continued)

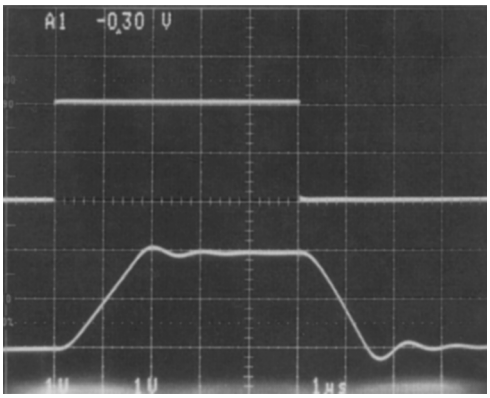
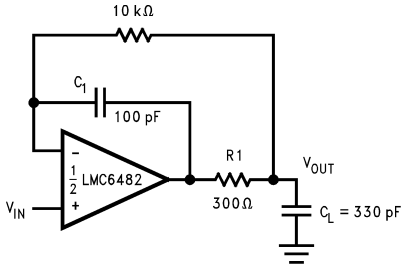


Figure 61. Pulse Response of the LMC6482-MIL Circuit in Figure 60

8.2.1.2.1.1 Capacitive Load Tolerance

The LMC6482-MIL can typically directly drive a 100-pF load with V_S = 15 V at unity gain without oscillating. The unity gain follower is the most sensitive configuration. Direct capacitive loading reduces the phase margin of op-amps. The combination of the output impedance of the op-amp and the capacitive load induces phase lag. This results in either an underdamped pulse response or oscillation.

Improved frequency response is achieved by indirectly driving capacitive loads, as shown in Figure 62.



Compensated to handle a 330pF capacitive load.

Figure 62. LMC6482-MIL Noninverting Amplifier

R1 and C1 serve to counteract the loss of phase margin by feeding forward the high-frequency component of the output signal back to the amplifiers inverting input, thereby preserving phase margin in the overall feedback loop. The values of R1 and C1 are experimentally determined for the desired pulse response. The resulting pulse response is shown in Figure 63.

Typical Applications (continued)

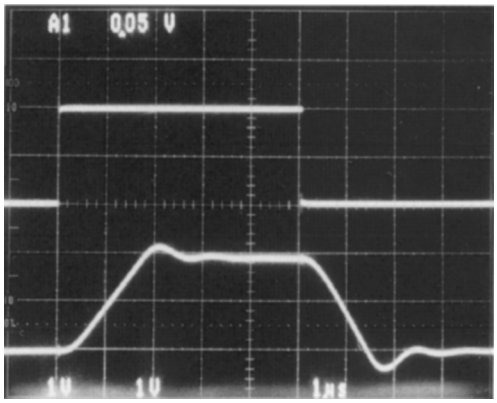


Figure 63. Pulse Response of LMC6482-MIL Circuit in Figure 62

8.2.1.2.1.2 Compensating for Input Capacitance

It is quite common to use large values of feedback resistance with amplifiers that have ultralow input current, like the LMC6482-MIL. Large feedback resistors can react with small values of input capacitance due to transducers, photo diodes, and circuits board parasitics to reduce phase margins.

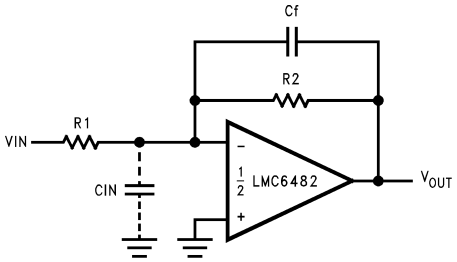


Figure 64. Canceling the Effect of Input Capacitance

The effect of input capacitance can be compensated for by adding a feedback capacitor. The feedback capacitor (as in Figure 64), C_f, is first estimated by:

$$\frac{1}{2\pi R_1 C_{IN}} \geq \frac{1}{2\pi R_2 C_f} \quad (1)$$

or

$$R_1 C_{IN} \leq R_2 C_f \quad (2)$$

which typically provides significant overcompensation.

Printed-circuit-board stray capacitance may be larger or smaller than that of a bread-board, so the actual optimum value for C_f may be different. The values of C_f should be checked on the actual circuit. (Refer to the LMC660 quad CMOS amplifier data sheet for a more detailed discussion.)

8.2.1.2.1.3 Offset Voltage Adjustment

Offset voltage adjustment circuits are illustrated in Figure 65 and Figure 66. Large value resistances and potentiometers are used to reduce power consumption while providing typically ±2.5 mV of adjustment range, referred to the input, for both configurations with V_S = ±5 V.

Typical Applications (continued)

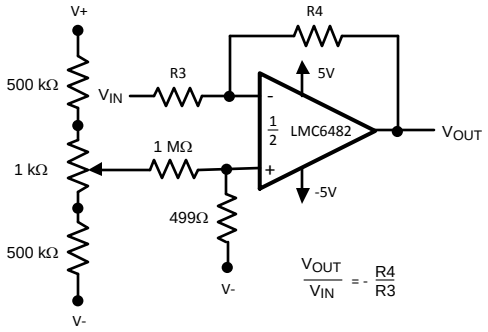


Figure 65. Inverting Configuration Offset Voltage Adjustment

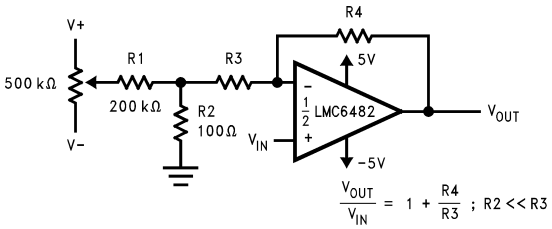


Figure 66. Noninverting Configuration Offset Voltage Adjustment

8.2.1.3 Application Curves

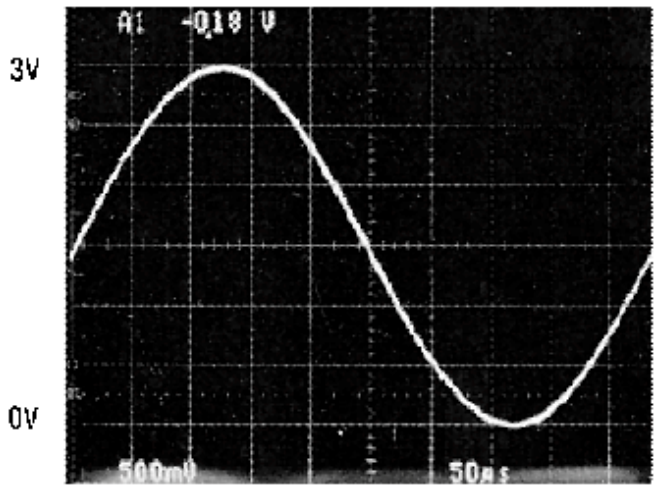


Figure 67. Rail-To-Rail Input

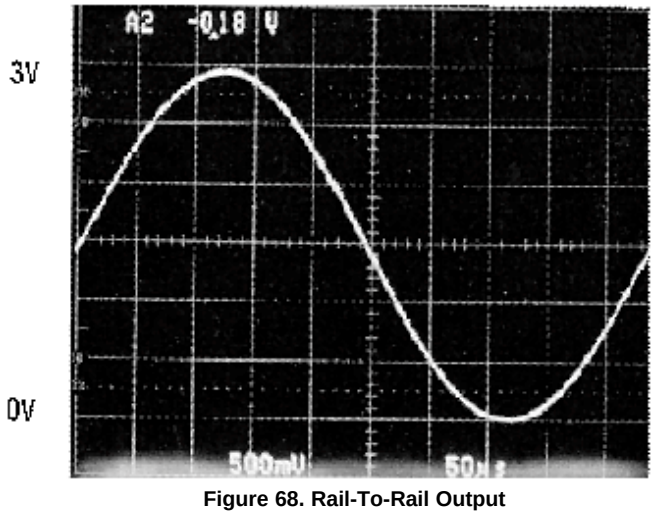


Figure 68. Rail-To-Rail Output

8.2.2 Typical Single-Supply Applications

The circuit in Figure 69 uses a single supply to half-wave rectify a sinusoid centered about ground. R_I limits current into the amplifier caused by the input voltage exceeding the supply voltage. Full-wave rectification is provided by the circuit in Figure 71.

Typical Applications (continued)

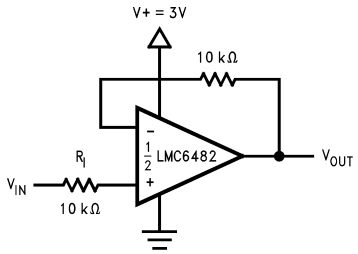


Figure 69. Half-Wave Rectifier With Input Current Protection (R_I)

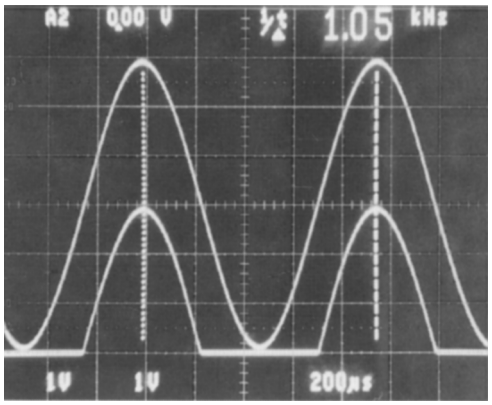


Figure 70. Half-Wave Rectifier Waveform

Typical Applications (continued)

In Figure 75 dielectric absorption and leakage is minimized by using a polystyrene or polyethylene hold capacitor. The droop rate is primarily determined by the value of C_H and diode leakage current. The ultralow input current of the LMC6482-MIL has a negligible effect on droop.

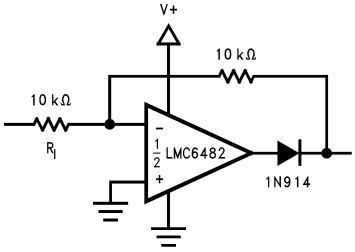


Figure 71. Full-Wave Rectifier With Input Current Protection (R_I)

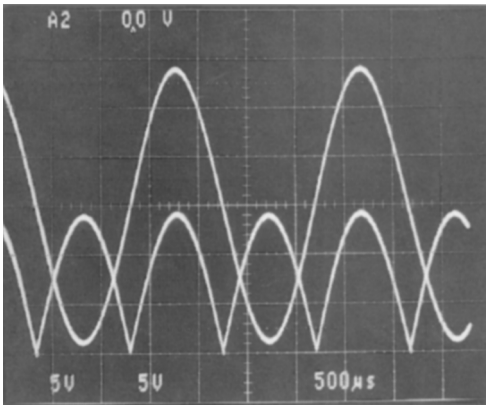


Figure 72. Full-Wave Rectifier Waveform

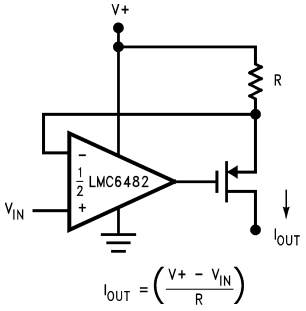


Figure 73. Large Compliance Range Current Source

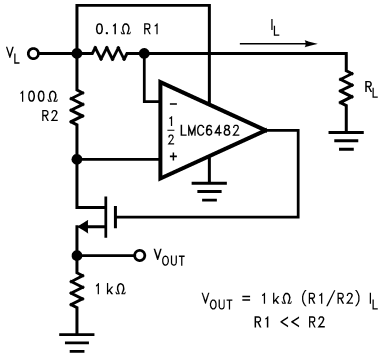


Figure 74. Positive Supply Current Sense

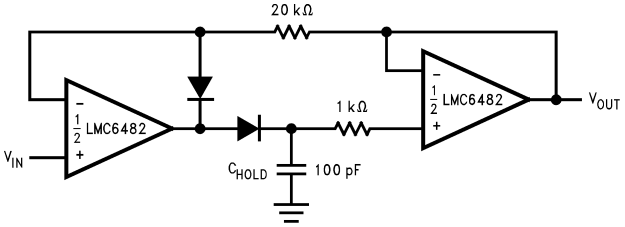


Figure 75. Low-Voltage Peak Detector With Rail-To-Rail Peak Capture Range

Typical Applications (continued)

The high CMRR (82 dB) of the LMC6482-MIL allows excellent accuracy throughout the rail-to-rail dynamic capture range of the circuit.

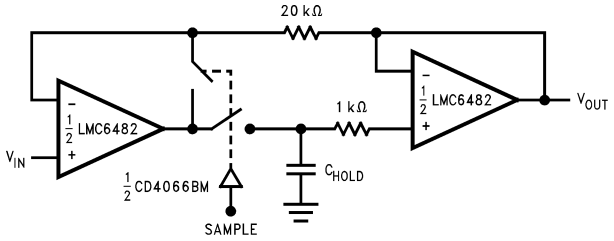


Figure 76. Rail-To-Rail Sample and Hold

The low-pass filter circuit in Figure 77 can be used as an anti-aliasing filter with the same voltage supply as the A/D converter.

Filter designs can also take advantage of the LMC6482-MIL ultralow input current. The ultralow input current yields negligible offset error even when large value resistors are used. This in turn allows the use of smaller valued capacitors which take less board space and cost less.

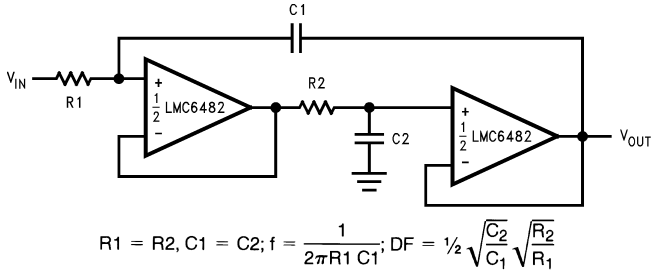


Figure 77. Rail-To-Rail Single Supply Low Pass Filter

9 Power Supply Recommendations

The LMC6482-MIL can be operated over a supply range of 3 V to 15 V. To achieve noise immunity as appropriate to the application, it is important to use good PCB layout practices for power supply rails and planes, as well as using bypass capacitors connected between the power supply pins and ground.

10 Layout

10.1 Layout Guidelines

It is generally recognized that any circuit which must operate with less than 1000 pA of leakage current requires special layout of the PC board. When one wishes to take advantage of the ultralow input current of the LMC6482-MIL, typically less than 20 fA, it is essential to have an excellent layout. Fortunately, the techniques of obtaining low leakages are quite simple. First, the user must not ignore the surface leakage of the PCB, even through it may sometimes appear acceptably low, because under conditions of high humidity or dust or contamination, the surface leakage will be appreciable.

To minimize the effect of any surface leakage, lay out a ring of foil completely surrounding the LM6482s inputs and the terminals of capacitors, diodes, conductors, resistors, relay terminals, and so forth connected to the inputs of the op-amp, as in Figure 78. To have a significant effect, guard rings should be placed on both the top and bottom of the PCB. This PC foil must then be connected to a voltage which is at the same voltage as the amplifier inputs, because no leakage current can flow between two points at the same potential. For example, a PCB trace-to-pad resistance of 10^{12} Ω, which is normally considered a very large resistance, could leak 5 pA if the trace were a 5-V bus adjacent to the pad of the input. This would cause a 250 times degradation from the actual performance of the LMC6482-MIL. However, if a guard ring is held within 5 mV of the inputs, then even a resistance of 10^{11} Ω would cause only 0.05 pA of leakage current. See Figure 79 through Figure 81 for typical connections of guard rings for standard op-amp configurations.

The designer should be aware that when it is inappropriate to lay out a PCB for the sake of just a few circuits, another technique is even better than a guard ring on a PCB: Do not insert the input pin of the amplifier into the PCB at all, but bend it up in the air and use only air as an insulator. Air is an excellent insulator. In this case you may have to forego some of the advantages of PCB construction, but the advantages are sometimes well worth the effort of using point-to-point up-in-the-air wiring. See Figure 82.

10.2 Layout Example

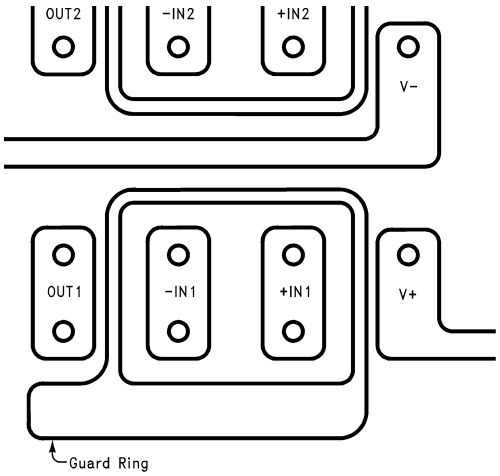


Figure 78. Example of Guard Ring in PCB Layout Typical Connections of Guard Rings

Layout Example (continued)

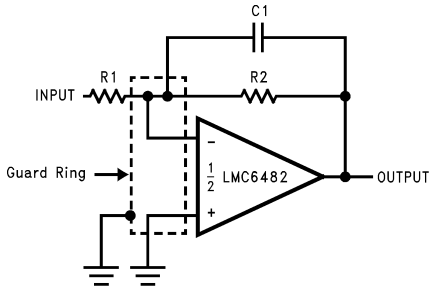


Figure 79. Inverting Amplifier Typical Connections of Guard Rings

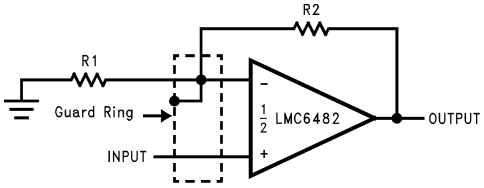


Figure 80. Noninverting Amplifier Typical Connections of Guard Rings

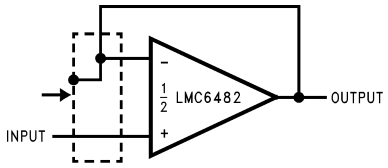
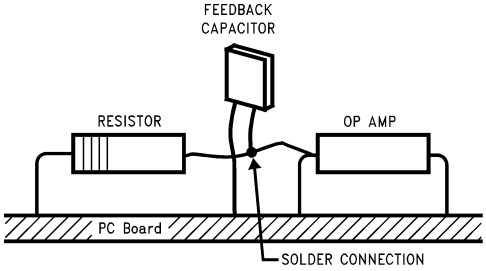


Figure 81. Follower Typical Connections of Guard Rings



(Input pins are lifted out of PCB and soldered directly to components. All other pins connected to PCB.)

Figure 82. Air Wiring

11 デバイスおよびドキュメントのサポート

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11.3 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMC6482AI MDA	ACTIVE	DIESALE	Y	0	324	RoHS & Green	Call TI	Level-1-NA-UNLIM	-40 to 85		Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

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RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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